NJW0281G (NPN) NJW0302G (PNP)

Complementary NPN-PNP Power Bipolar Transistors

These complementary devices are lower power versions of the popular NJW3281G and NJW1302G audio output transistors. With superior gain linearity and safe operating area performance, these transistors are ideal for high fidelity audio amplifier output stages and other linear applications.

Features

- Exceptional Safe Operating Area
- NPN/PNP Gain Matching within 10% from 50 mA to 3 A
- Excellent Gain Linearity
- High BVCEO
- High Frequency
- These Devices are Pb-Free and are RoHS Compliant

Benefits

- Reliable Performance at Higher Powers
- Symmetrical Characteristics in Complementary Configurations
- Accurate Reproduction of Input Signal
- Greater Dynamic Range
- High Amplifier Bandwidth

Applications

- High-End Consumer Audio Products
 - Home Amplifiers
 - Home Receivers
- Professional Audio Amplifiers
 - Theater and Stadium Sound Systems
 - Public Address Systems (PAs)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	250	Vdc
Collector-Base Voltage	V _{CBO}	250	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector-Emitter Voltage - 1.5 V	V _{CEX}	250	Vdc
Collector Current - Continuous	I _C	15	Adc
Collector Current - Peak (Note 1)	I _{CM}	30	Adc
Base Current - Continuous	I _B	1.5	Adc
Total Power Dissipation @ T _C = 25°C	P _D	150	Watts
Operating and Storage Junction Temperature Range	T _J , T _{stg}	- 65 to +150	°C

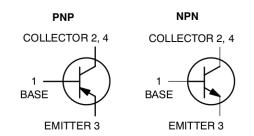
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

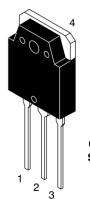
1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle < 10%.



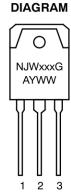
http://onsemi.com

15 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS, 150 WATTS





TO-3P CASE 340AB STYLES 1,2,3



MARKING

xxxx = 0281 or 0302
G = Pb-Free Package
A = Assembly Location
Y = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
NJW0281G	TO-3P (Pb-Free)	30 Units/Rail
NJW0302G	TO-3P (Pb-Free)	30 Units/Rail

NJW0281G (NPN) NJW0302G (PNP)

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	0.83	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				•
Collector–Emitter Sustaining Voltage (I _C = 30 mA, I _B = 0)	V _{CEO(sus)}	250	-	V
Collector Cutoff Current (V _{CB} = 250 V, I _E = 0)	Ісво	-	10	μА
Emitter Cutoff Current $(V_{EB} = 5.0 \text{ V, } I_{C} = 0)$	I _{EBO}	-	5.0	μА
ON CHARACTERISTICS			•	
DC Current Gain (I _C = 0.5 A, V _{CE} = 5.0 V) (I _C = 1.0 A, V _{CE} = 5.0 V) (I _C = 3.0 A, V _{CE} = 5.0 V)	h _{FE}	75 75 75	150 150 150	-
Collector–Emitter Saturation Voltage (I _C = 5.0 A, I _B = 0.5 A)	V _{CE(sat)}	-	1.0	V
Base-Emitter On Voltage (I _C = 5.0 A, V _{CE} = 5.0 V)	V _{BE(on)}	-	1.2	V
DYNAMIC CHARACTERISTICS			•	•
Current-Gain – Bandwidth Product (I _C = 1.0 A, V _{CE} = 5.0 V, f _{test} = 1.0 MHz)	f _⊤	30	-	MHz
Output Capacitance (V _{CB} = 10 V, I _E = 0, f _{test} = 1.0 MHz)	C _{ob}	-	400	pF

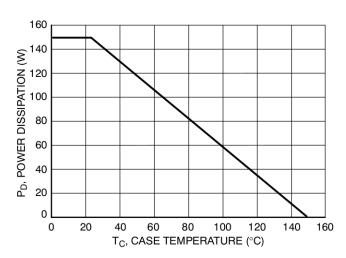


Figure 1. Power Derating

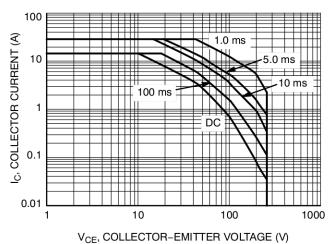


Figure 2. Safe Operating Area

NJW0281G (NPN) NJW0302G (PNP)

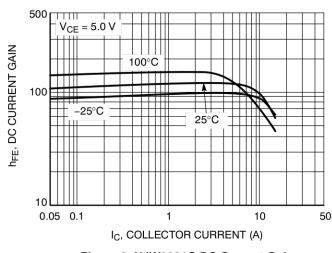


Figure 3. NJW0281G DC Current Gain

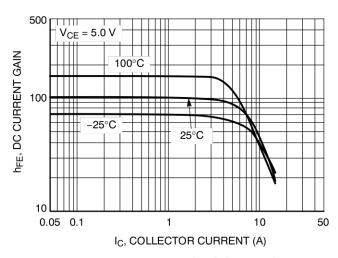


Figure 4. NJW0302G DC Current Gain

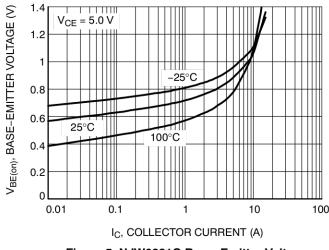


Figure 5. NJW0281G Base-Emitter Voltage

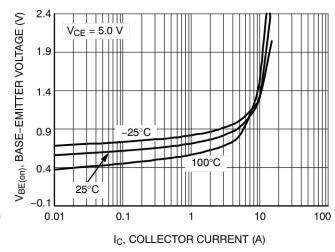


Figure 6. NJW0302G Base-Emitter Voltage

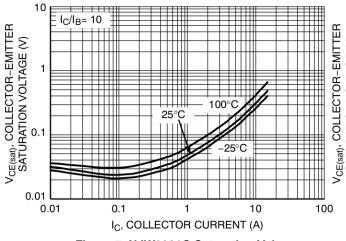


Figure 7. NJW0281G Saturation Voltage

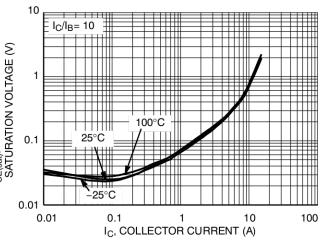


Figure 8. NJW0302G Saturation Voltage

NJW0281G (NPN) NJW0302G (PNP)

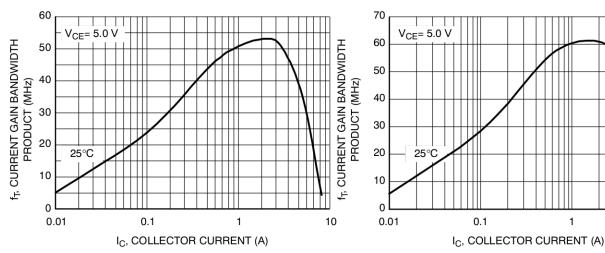
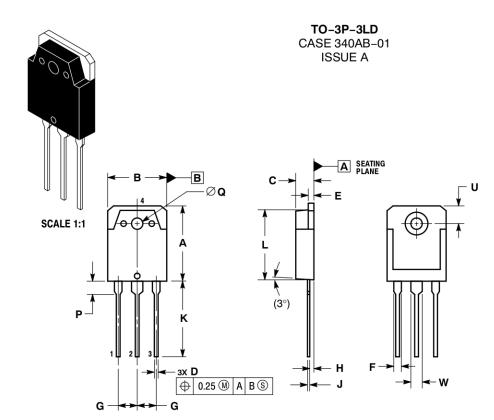


Figure 9. NJW0281G Current Gain Bandwidth Product

Figure 10. NJW0302G Current Gain Bandwidth Product

10

DATE 30 OCT 2007



- OTES.

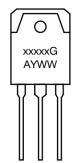
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS

 3. DIMENSION & APPLIES TO PLATED TERMINAL
- AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM THE TERMINAL TIP.
- DIMENSION A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	19.70	19.90	20.10	
В	15.40	15.60	15.80	
С	4.60	4.80	5.00	
D	0.80	1.00	1.20	
Е	1.45	1.50	1.65	
F	1.80	2.00	2.20	
G	5.45 BSC			
Н	1.20	1.40	1.60	
J	0.55	0.60	0.75	
K	19.80	20.00	20.20	
L	18.50	18.70	18.90	
Р	3.30	3.50	3.70	
Q	3.10	3.20	3.50	
U	5.00 REF			
W	2.80	3.00	3.20	

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Pb-Free Package G = Assembly Location Α

= Year WW = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

STYLE 1: PIN 1. BASE 2. COLLECTOR

- EMITTER
- COLLECTOR

STYLE 2: ANODE CATHODE PIN 1. ANODE

CATHODE

STYLE 3: PIN 1. GATE 2. DRAIN SOURCE DRAIN

DOCUMENT NUMBER:	98AON25095D	Electronic versions are uncontrolled except when accessed directly from the Document Reposito Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TO-3P-3LD		PAGE 1 OF 1

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify an

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada

Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative